## : ©hipsmall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation, and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!


## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODE

MAIN PRODUCT CHARACTERISTICS

| $\mathrm{I}_{\mathrm{F}(\mathrm{AV})}$ | 1.5 A |
| :---: | :---: |
| $\mathrm{~V}_{\mathrm{RRM}}$ | 200 V |
| $\mathrm{Tj}_{\mathrm{max}}$ (max | $150^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\mathrm{F}}(\max )$ | 0.85 V |

## FEATURES AND BENEFITS

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- The specifications and curves enable the determination of trr and $\mathrm{I}_{\mathrm{RM}}$ at $100^{\circ} \mathrm{C}$ under users conditions.



## DESCRIPTION

Low voltage drop and rectifier suited for switching mode base drive and transistor circuits.

ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| VRRM | Repetitive peak reverse voltage |  | 200 | V |
| IfRM | Repetitive peak forward current * | $\mathrm{tp}=5 \mu \mathrm{~s} \quad \mathrm{~F}=1 \mathrm{KHz}$ | 80 | A |
| $\mathrm{IF}_{\text {( }} \mathrm{AV}$ ) | Average forward current* | $\mathrm{Ta}=95^{\circ} \mathrm{C} \delta=0.5$ | 1.5 | A |
| IFSM | Surge non repetitive forward current | tp=10 ms Sinusoidal | 50 | A |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature range |  | $-65+150$ | ${ }^{\circ} \mathrm{C}$ |
| Tj | Maximum operating junction temperature |  | + 150 | ${ }^{\circ} \mathrm{C}$ |
| TL | Maximum lead temperature for soldering during 10s at 4 mm from case |  | 230 | ${ }^{\circ} \mathrm{C}$ |

[^0]THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {th }(\mathrm{j}-\mathrm{a})}$ | Junction to ambient* | 45 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

* On infinite heatsink with 10 mm lead length.


## STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Tests conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{IR}^{*}$ | Reverse leakage current | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | $\mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\text {RRM }}$ |  |  | 10 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{Tj}=100^{\circ} \mathrm{C}$ |  |  |  | 0.5 | mA |
| $\mathrm{V}_{\mathrm{F}}$ ** | Forward voltage drop | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=4.5 \mathrm{~A}$ |  |  | 1.2 | V |
|  |  | $\mathrm{Tj}=100^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=1.5 \mathrm{~A}$ |  | 0.78 | 0.85 |  |

Pulse test : * tp $=5 \mathrm{~ms}, \delta<2 \%$
** $\mathrm{tp}=380 \mu \mathrm{~s}, \delta<2 \%$

To evaluate the maximum conduction losses use the following equation :
$\mathrm{P}=0.75 \times \mathrm{I}_{\mathrm{F}(\mathrm{AV})}+0.075 \times \mathrm{I}_{\mathrm{F}}{ }^{2}(\mathrm{RMS})$

## RECOVERY CHARACTERISTICS

| Symbol | Tests conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| trr | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{Adim} / \mathrm{dt}=-50 \mathrm{~A} / \mu \mathrm{s} \quad \mathrm{V}_{\mathrm{R}}=30 \mathrm{~V}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ |  |  | 35 | ns |
| tfr | $\mathrm{I}_{\mathrm{F}}=1.5 \mathrm{~A} \quad \mathrm{dl}_{\mathrm{F}} / \mathrm{dt}=-50 \mathrm{~A} / \mathrm{\mu s}$ $\text { Measured at } 1.1 \times V_{F m a x}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ |  | 30 |  | ns |
| $V_{\text {FP }}$ | $\mathrm{IF}_{\mathrm{F}}=1.5 \mathrm{Ad} \mathrm{dF} / \mathrm{dt}=-50 \mathrm{~A} / \mu \mathrm{s}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ |  | 5 |  | V |
| Qrr | $\mathrm{I}_{\mathrm{F}}=1.5 \mathrm{AdF} / \mathrm{dt}=-20 \mathrm{~A} / \mu \mathrm{s} \quad \mathrm{V}_{\mathrm{R}} \leq 30 \mathrm{~V}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ |  | 10 |  | nC |

Fig. 1: Average forward power dissipation versus average forward current.


Fig. 3: Thermal resistance versus lead length.


Fig. 5: Forward voltage drop versus forward current (maximum values).


Fig. 2: Average forward current versus ambient temperature $(\delta=0.5)$.


Fig. 4: Variation of thermal impedance junction to ambient versus pulse duration (recommended pad layout, epoxy FR4, e(Cu) $=35 \mu \mathrm{~m})$.


Fig. 6: Junction capacitance versus reverse voltage applied (typical values).


Fig. 7: Reverse recovery time versus $\mathrm{dl}_{\mathrm{F}} / \mathrm{dt}$.


Fig. 8: Peak reverse recovery current versus $\mathrm{dl}_{\mathrm{F} / \mathrm{dt} \text {. }}$


Fig. 9: Dynamic parameters versus junction temperature.


## PACKAGE MECHANICAL DATA

DO-15


| REF. | DIMENSIONS |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Millimeters |  | Inches |  |
|  | Min. | Max. | Min. | Max. |
| A | 6.05 | 6.75 | 0.238 | 0.266 |
| B | 2.95 | 3.53 | 0.116 | 0.139 |
| C | 26 | 31 | 1.024 | 1.220 |
| D | 0.71 | 0.88 | 0.028 | 0.035 |


| Ordering code | Marking | Package | Weight | Base qty | Delivery mode |
| :---: | :---: | :---: | :---: | :---: | :---: |
| BYW100-200 | BYW100-200 | DO-15 | 0.4 g | 1000 | Ammopack |
| BYW100-200RL | BYW100-200 | DO-15 | 0.4 g | 6000 | Tape and reel |

- White band indicates cathode
- Epoxy meets UL 94,V0

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied.
STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics
© 2001 STMicroelectronics - Printed in Italy - All rights reserved.
STMicroelectronics GROUP OF COMPANIES
Australia - Brazil - Canada - China - Finland - France - Germany
Hong Kong - India - Israel - Italy - Japan - Malaysia -Malta - Morocco - Singapore
Spain - Sweden - Switzerland - United Kingdom - United States.
http://www.st.com


[^0]:    * On infinitive heatsink with 10 mm lead length

